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TOSHIBA Photocoupler GaAs Ired & Photo-Thyristor

TLP541G,TLP542G

Programmable Controllers AC-Output Module

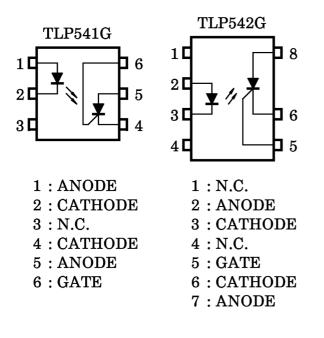
Solid State Relay

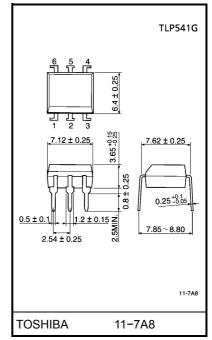
The TOSHIBA TLP541G consists of a photo-thyristor optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

The TOSHIBA TLP542G consists of a photo-thyristor optically coupled to a gallium arsenide infrared emitting diode in a seven lead plastic DIP package.

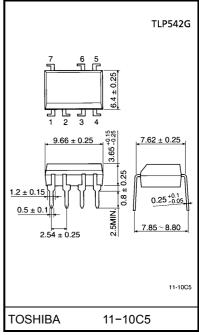
- Peak off-state voltage: 400 V (min.)
- Trigger LED current: 7 mA (max.)
- On-state current: 150 mA (max.)
- Isolation voltage: 2500 V_{rms} (min.)
- UL recognized: UL1577, file no. E67349

Pin Configuration (top view)











Unit in mm

Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	١ _F	70	mA
	Forward current derating (Ta ≥ 25°C)	ΔI _F / °C	-0.7	mA / °C
LED	Peak forward current (100 µs pulse, 100 pps)	I _{FP}	1	А
1	Reverse voltage	V _R	5	V
	Junction temperature	Tj	125	°C
Detector	Peak forward voltage (R_{GK} = 27k Ω)	V _{DRM}	400	V
	Peak reverse voltage (R_{GK} = 27k Ω)	V _{RRM}	400	V
	On-state current	I _{T (RMS)}	150	mA
	On–state current derating (Ta ≥ 25°C)	ΔI _T / °C	-2.0	mA / °C
	Peak one cycle surge current	I _{TSM}	2	Α
	Peak reverse gate voltage	V _{GM}	-5	V
	Junction temperature	Tj	100	°C
Storag	Storage temperature range		-55~125	°C
Operat	ting temperature range	T _{opr}	-30~100	°C
Lead s	oldering temperature (10 s)	T _{sol}	260	°C
Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note)		BVS	2500	V _{rms}

(Note) Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{AC}	_	_	120	V _{ac}
Forward current	١ _F	10	16	25	mA
Operating temperature	T _{opr}	-30	_	85	°C
Gate to cathode resistance	R _{GK}	_	27	33	kΩ
Gate to cathode capacity	C _{GK}		0.01	0.1	μF

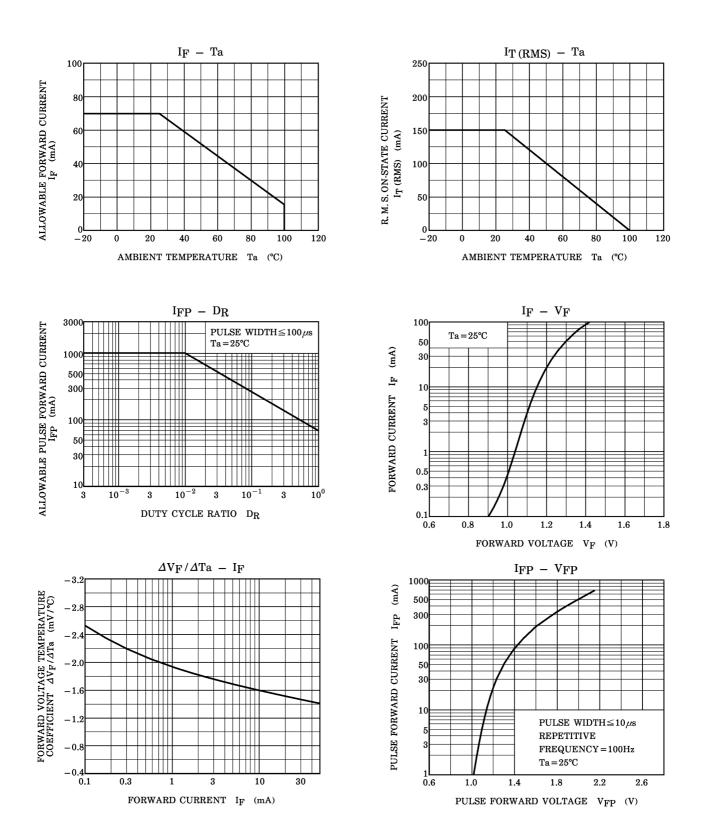
Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition		Min.	Тур.	Max.	Unit
LED	Forward voltage	V _F	I _F = 10 mA		1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V			_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz		_	30	_	pF
Detector	Off-state current	I _{DRM}	V _{AK} = 400 V R _{GK} = 27 kΩ	Ta = 25°C	_	10	5000	nA
				Ta = 100°C		1	100	μA
	Reverse current	I _{RRM}	$ \begin{array}{c} V_{KA} = 400 \ V \\ R_{GK} = 27 \ k\Omega \end{array} & \begin{array}{c} Ta = 25^{\circ}C \\ Ta = 100^{\circ}C \end{array} $	Ta = 25°C		10	5000	nA
				Ta = 100°C	-	1	100	μA
	On-state voltage	V _{TM}	I _{TM} = 100 mA		_	0.9	1.3	V
	Holding current	Iн	R _{GK} = 27 kΩ			0.2	1	mA
	Off-state dv/dt	dv/dt	V _{AK} = 280 V, R _{GK} = 27 kΩ		5	10	_	V/µs
		V = 0, f = 1 MHz A	node to gate	_	20	—	- 5	
	Capacitance	Cj	G	ate to cathode	-	350	—	pF

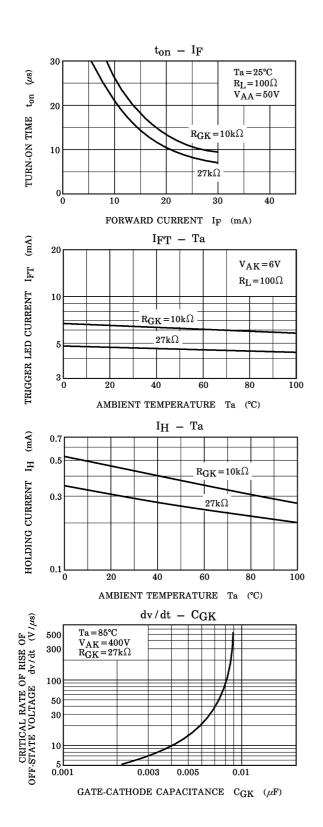
Coupled Characteristics (Ta = 25°C)

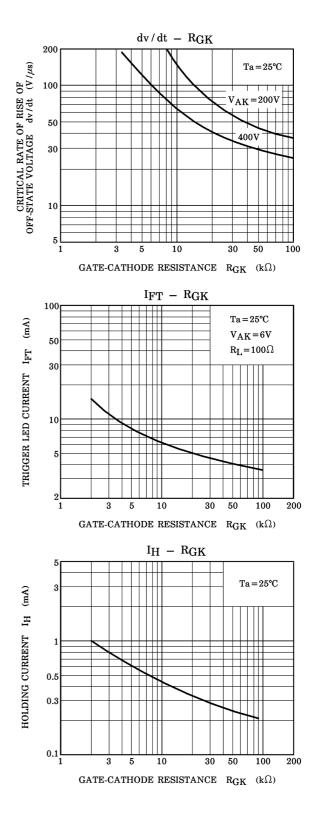
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	V_{AK} = 6 V, R_{GK} = 27 k Ω	1	4	7	mA
Turn-on time	t _{on}	I_F = 50 mA, R_{GK} = 27 kΩ	_	10	—	μs
Capacitance (input to output)	C _S	V _S = 0, f = 1 MHz		0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	_	10 ¹¹	_	Ω
Isolation voltage	BVS	AC, 1 minute	2500	_	_	V _{rms}

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